To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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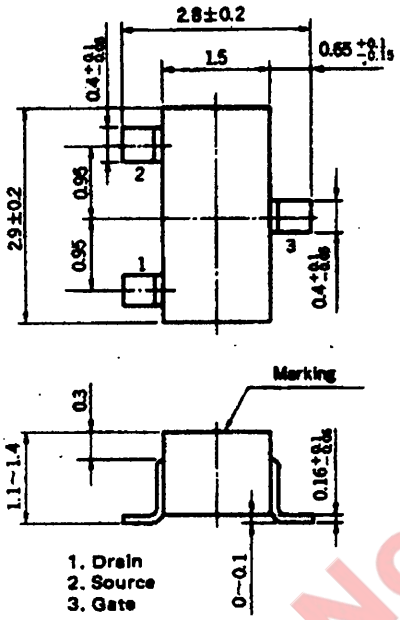
(Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

RENESAS

JUNCTION FIELD EFFECT TRANSISTOR
2SK515

AUDIO FREQUENCY AMPLIFIER
N-CHANNEL SILICON JUNCTION FIELD EFFECT TRANSISTOR
MINI MOLD

PACKAGE DIMENSIONS
in millimeters



FEATURES

- High Voltage V_{DSX} = 50 V
- High $|y_{fs}|$ $|y_{fs}|$ = 4.1 mS TYP.

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents (T_a = 25 °C)

Gate to Drain Voltage	V_{GDO}	−50	V
Gate to Source Voltage	V_{GSO}	−50	V
Drain to Source Voltage (V_{GS} = −5.0 V)	V_{DSX}	50	V
Drain Current (DC)	I_D	20	mA
Gate Current (DC)	I_G	10	mA
Maximum Power Dissipation			
Total Power Dissipation			
at 25 °C Ambient Temperature	P_T	150	mW
Maximum Temperatures			
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_{stg}	−55 to +125	°C

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Gate Cutoff Current	I_{GSS}			−1.0	nA	V_{GS} = −30 V, V_{DS} = 0
Zero-Gate Voltage Drain Current	I_{DSS}	1.0	3.5	12	mA	V_{DS} = 5.0 V, V_{GS} = 0
Gate to Source Cutoff Voltage	$V_{GS(off)}$	−0.5	−1.7	−4.5	V	V_{DS} = 5.0 V, I_D = 0.1 μA
Forward Transfer Admittance	$\|y_{fs}\|_1$	1.2	1.8		mS	V_{DS} = 5.0 V, I_D = 0.5 mA, f = 1.0 kHz
Forward Transfer Admittance	$\|y_{fs}\|_2$	1.4	4.1		mS	V_{DS} = 5.0 V, V_{GS} = 0, f = 1.0 kHz
Input Capacitance	C_{iss}		6.0		pF	V_{DS} = 10 V, V_{GS} = 0, f = 1.0 MHz
Feedback Capacitance	C_{rss}		1.5		pF	V_{DS} = 10 V, V_{GS} = 0, f = 1.0 MHz

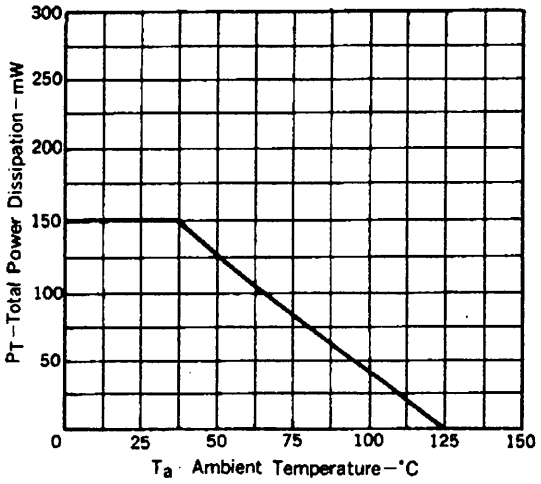
I_{DSS} Classification

Marking	X31	X32	X33	X34	X35
I_{DSS}(mA)	1.0 to 2.0	1.5 to 3.0	2.5 to 5.0	4.0 to 8.0	6.0 to 12

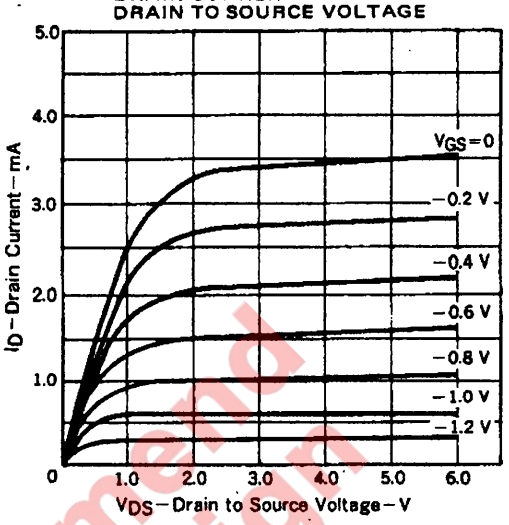
NEC Corporation

TYPICAL CHARACTERISTICS (T_a = 25 °C)

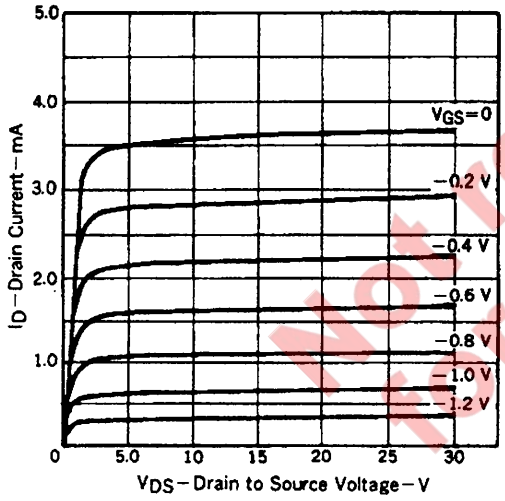
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



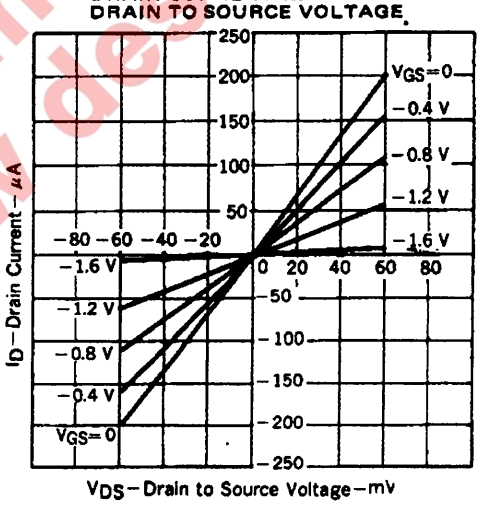
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



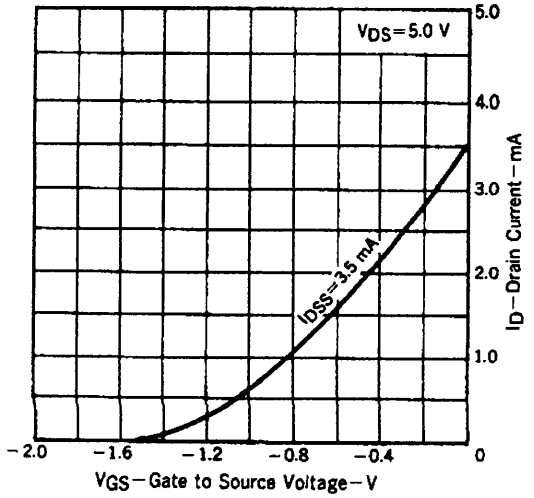
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



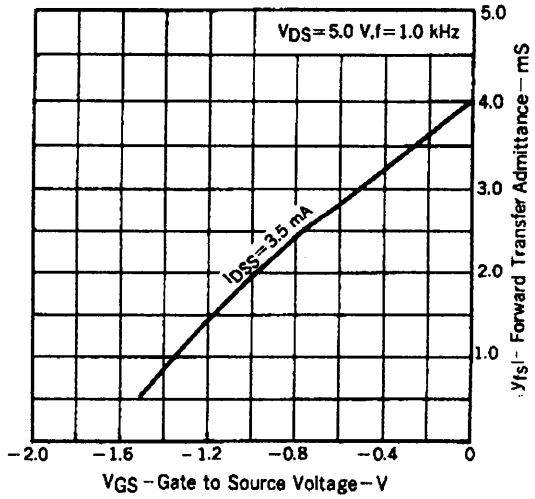
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



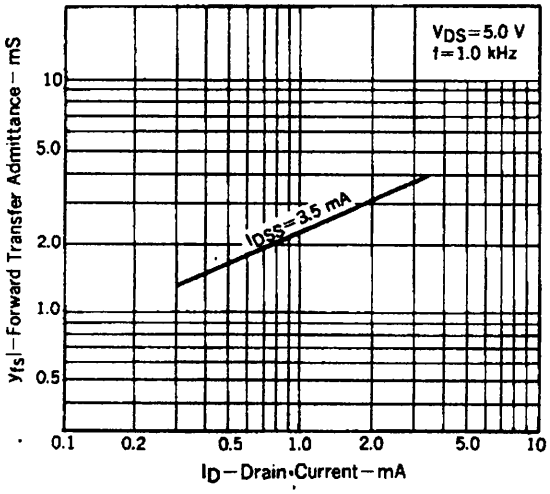
DRAIN CURRENT vs. GATE TO SOURCE VOLTAGE



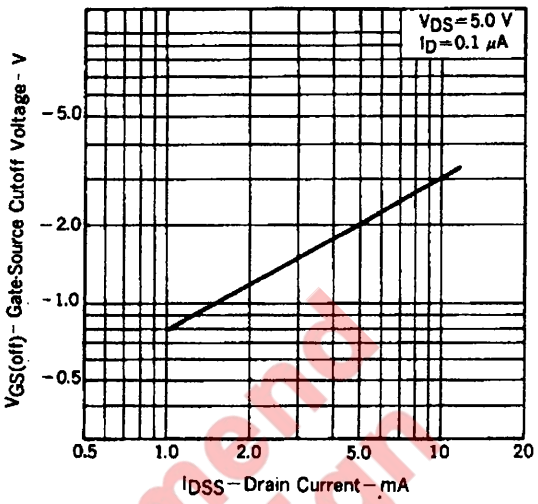
FORWARD TRANSFER ADMITTANCE (Y_{fs}) vs. GATE TO SOURCE VOLTAGE



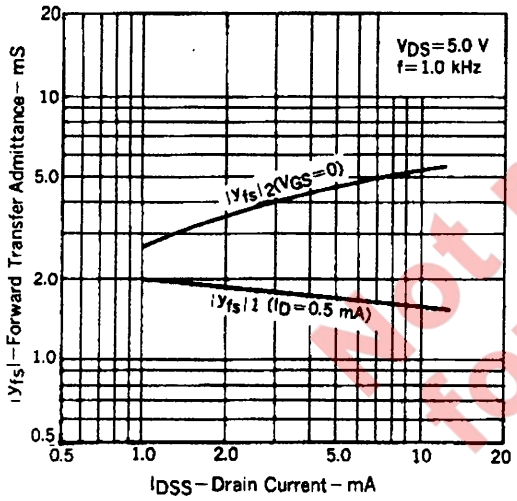
FORWARD TRANSFER ADMITTANCE (y_{fs}) vs. DRAIN CURRENT



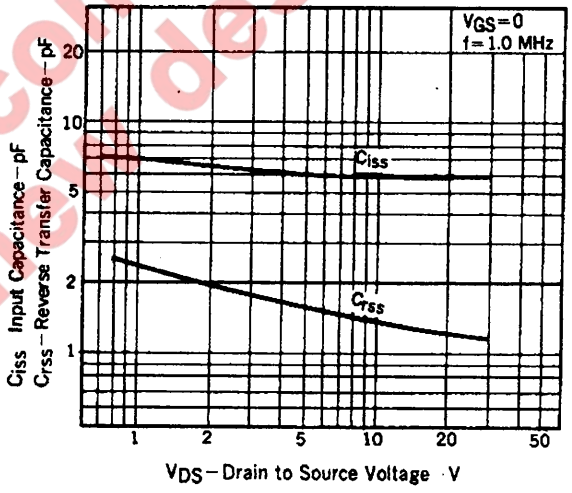
GATE-SOURCE CUTOFF VOLTAGE vs. ZERO-GATE VOLTAGE DRAIN CURRENT CO-RELATION



FORWARD TRANSFER ADMITTANCE (y_{fs}) vs. ZERO-GATE VOLTAGE DRAIN CURRENT CO-RELATION



INPUT AND REVERSE TRANSFER CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



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TC–1652
JULY–15–85M
Printed in Japan